## Synthesis and characterization of ZnO/ZnS/MoS<sub>2</sub> core-shell nanowires

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### Abstract

Hybrid nanostructures composed of layered materials have recently attracted a lot of attention due to their promising electronic and catalytic properties. In this study, we describe a novel synthesis strategy of ZnO/ZnS/MoS<sub>2</sub> core-shell nanowire growth using a three-step route. First, ZnO nanowire array was grown on a silicon wafer. Second, the sample was immersed in ammonium molybdate solution and dried. At the third step, the sample was annealed in a sulfur atmosphere at 700 °C. Two solid state chemical reactions occur simultaneously during the annealing and result in a formation of ZnS and MoS<sub>2</sub> phases. Produced ZnO/ZnS/MoS<sub>2</sub> coreshell nanowires were characterized by scanning and transmission electron microscopy, whereas their chemical composition was confirmed by selected area electron diffraction and micro-Raman spectroscopy.

Keywords:

A1 Characterization; A1 Crystal morphology; A1 Nanostructures; B1 Oxides; B1 Sulfides; B1 Zinc compounds. 1. Introduction.

Recent advances in research of layered materials, as for example, graphene, have stimulated studies of two-dimensional (2D) transition metal dichalcogenides (TMDs) with unique properties that do not exist in their bulk counterparts [1, 2]. TMDs, such as  $MS_2$  (M = W, Mo), are indirect bandgap semiconductors in bulk form, however, when scaled down to monolayers, a direct energy bandgap emerges due to quantum confinement effects [2, 3].  $WS_2$  and  $MoS_2$  monolayers are widely studied due to their unique optical [4, 5] and electronic [6] properties and potential applications in electronics and optoelectronics [7, 8].

MoS<sub>2</sub> probably is the most explored TMD. It can be synthesized in a form of powder, polycrystalline film, 2D nanosheets and nanotubes [9]. MoS<sub>2</sub> is an n-type semiconductor having the indirect and direct band gaps of  $E_{ig} = 1.2$  eV and  $E_{dg} = 1.8$  eV, respectively. MoS<sub>2</sub> is also chemically inert, thermally stable and not toxic [10].

Zinc oxide (ZnO) nanowires (NWs), that have been in focus of scientific community for decades, are still gaining increased attention due to the simplicity of synthesis and a number of beneficial properties. Among other applications, ZnO NWs can be used as a template for the synthesis of heterostructured nanomaterials [11]. Zinc oxide has two main phases: hexagonal wurtzite and cubic zincblende. Wurtzite is the most common and most stable structure, while zincblende form grows on substrates with cubic lattice structure. Bulk ZnO is known to be a direct band gap (3.2–3.3 eV) n-type semiconductor [12].

It is known that the use of core-shell materials with the shell having higher band gap leads to an enhancement of optical properties. Band gap of zinc sulfide (ZnS) for both zincblende (3.7 eV) and wurtzite (3.9 eV) forms is wider than that of ZnO at room temperature [13]. Therefore, ZnS is frequently used to improve luminescent properties of ZnO [14]. There are many methods to produce ZnS shell around ZnO core [15], and one of them is direct sulfidation process as it was demonstrated in [16].

Recently, several groups reported on wet chemical synthesis of  $ZnO-MoS_2$  hybrid heterostructures [17, 18, 19]. In these studies, superior photocatalytic properties of  $ZnO-MoS_2$ hybrid heterostructures were demonstrated, in particular for photocatalytic hydrogen evolution reaction and photodegradation of methylene blue and other organic dyes. Also direct coupling between ZnO nanorods and  $MoS_2$  monolayers was used in [20] to enhance Raman and photoluminescence emission.

In this study we report for the first time on the synthesis of  $ZnO/ZnS/MoS_2$  core-shell NWs by immersion of ZnO NWs in the solution of ammonium molybdate followed by annealing in

the sulfur atmosphere. Such ZnO/ZnS/MoS<sub>2</sub> core-shell nanostructures could potentially be applied for photocatalytic hydrogen evolution reaction and in dye-sensitized-like solar cells. 2. Experimental details.

 $ZnO/ZnS/MoS_2$  core-shell nanowires were produced by a three-step route: 1) synthesis of ZnO NWs on a silicon wafer, 2) immersion of the ZnO NW sample in ammonium molybdate solution, 3) annealing of the sample in sulfur atmosphere.

ZnO NWs were grown by a chemical vapour transport method using spherical Au nanoparticles as a catalyst (Smart materials, water suspension, 50 nm in diameter) [10]. A 1:4 mixture of ZnO and graphite powders was heated to 900 °C in a quartz tube for 30 min in a stream of the carrier gas N<sub>2</sub>. Nanowires were synthesized on an oxidized silicon wafers Si(100)/SiO<sub>2</sub> (Semiconductor Wafer, Inc.). At the next step, the samples were immersed into the solution of 0.125 g ammonium heptamolybdate  $(NH_4)_6Mo_7O_{24}\cdot4H_2O$  in 20 ml H<sub>2</sub>O and subsequently dried at room temperature. It is known that ammonium heptamolybdate decomposes at 350-400 °C with a formation of MoO<sub>3</sub> [21]. Therefore, finally, the samples were annealed in a quartz tube in the sulfur atmosphere during 0.5 hour at 700 °C to convert the molybdenum precursor (MoO<sub>3</sub>) into MoS<sub>2</sub>. Additional sample was prepared by annealing in the sulfur atmosphere during 0.5 hour at 500 °C to compare quality of MoS<sub>2</sub> shell at lower synthesis temperatures [22].

Morphology of pure ZnO and core-shell NWs on a silicon substrate was characterized by scanning electron microscopy (SEM, Lyra, Tescan). The inner crystalline structure of core-shell NWs was revealed using transmission electron microscopy (TEM, Tecnai GF20, FEI) operated at the accelerating voltage of 200 kV. The diffraction pattern was processed by CrysTBox software [23]. Confocal imaging and micro-Raman measurements were performed with confocal microscope with spectrometer Nanofinder-S (SOLAR TII). A diode pumped solid-state (DPSS) Nd:YAG laser (532 nm, max continuous wave (cw) power  $P_{ex} = 150$  mW) was used as the excitation source. A Peltier-cooled back-thinned CCD camera (ProScan HS-101H) was used for

detection of Raman spectra. All measurements were performed in a back-scattering geometry through a Nikon CF Plan Apo  $100 \times (NA = 0.95)$  optical objective.

2D MoS<sub>2</sub> nanosheets used as the reference sample were grown using a similar chemical vapour transport process in a quartz tube with a temperature gradient. Powders of MoO<sub>3</sub> (1 mg) and sulfur (0.25 g) were employed as solid sources: MoO<sub>3</sub> was heated to 700 °C and sulfur to 300 °C. Silicon substrate was placed downstream of precursors in the high-temperature zone (700 °C). At the end of the growth process, the furnace was let to cool down to the room temperature naturally. The gas flow rate was held constant throughout the procedure. The optimal growth parameters for the synthesis procedure of MoS<sub>2</sub> nanosheets were found to be 20 minutes at 700°C in the high-temperature zone.

Freshly grown  $MoS_2$  nanosheets were studied by Eclipse L150 (Nikon) optical microscope; for higher resolution and contrast images SEM (Tescan, Vega II) was used. The thickness of prepared nanostructures was determined by atomic force microscope (AFM, CP-II, Veeco) in the tapping mode using PPP-NCHR probes with force constant 42 N/m and tip radius of curvature < 10 nm (Nanosensors).

3. Results and discussion.

SEM was used to control the growth of pure ZnO NWs and the change of their morphology after subsequent annealing in the sulfur atmosphere. It is clearly visible that the smooth surface of ZnO NWs, immersed in the ammonium heptamolybdate solution, (Fig. 1(a,b)) becomes significantly more rough and altered (Fig. 1(c,d)) after annealing.

Strong electrical charging was observed for the core-shell NWs, however was absent for pure ZnO NWs sample and sample immersed in the ammonium heptamolybdate solution. This may indicate that electrical properties of ZnO NWs were strongly affected by a shell layer, making them less conductive. It is known that sulfur reacts with ZnO at temperatures above 400 °C resulting in a formation of ZnS phase [16], which has the value of the bang gap (3.7 eV)

larger than ZnO (3.4 eV) [13]. Alternatively,  $MoS_2$  shell may be responsible for electrical charging.

SEM images of 2D  $MoS_2$  nanosheets with triangular and star shapes grown on  $Si(100)/SiO_2$  wafer at 700 °C are shown in Fig. 1(e,f). These  $MoS_2$  nanosheets were prepared as a reference sample for Raman spectroscopy.

TEM images of core-shell NWs annealed in sulfur atmosphere at 500 °C and 700 °C are shown in Fig. 2. Sample annealed at 500 °C has polycrystalline shell structure of zincblende ZnS, with remaining amorphous phase (Supplementary materials, Fig. S1). No MoS<sub>2</sub> shell was found around the NW, however few crystallites appearing as parallel black lines (Fig. 2(c)) may be identified as MoS<sub>2</sub>.

It is easy to see that the shell is non-homogeneous and appears as a mosaic of dark and bright spots (Fig. 2(d,e)) or as microcrystals formed around the NW core (Fig. 2(g,h)) for the sample annealed at 700 °C. Analysis of selected area electron diffraction (SAED) image of a core-shell NW (Fig. 3) reveals the following phases: ZnO zincite (zone axis <001>), ZnS zincblende (zone axis <001>), and MoS<sub>2</sub> molybdenite phases (zone axis <-2201> and <14-53>). Dominating (most intensive) diffraction spots belong to the ZnO core, while less intensive to ZnS and MoS<sub>2</sub> phases. Symmetric orientation of MoS<sub>2</sub> reflexes relative to ZnO reflexes may indicate epitaxial growth of MoS<sub>2</sub>.

According to interplanar distance measurements and SAED analysis data, microcrystals on NW surface can be attributed to zincblende ZnS phase with the interplanar distance d=3.1-3.2 Å [16, 24]. Due to the lattice mismatch and different crystal structure of ZnO core and ZnS shell, the upper layer cannot grow as a smooth single crystal layer on top of ZnO NW surface.

We found that samples prepared at 700 °C are coated by a thin layer of  $MoS_2$ , which appears as a number of parallel black lines ( $MoS_2$  monolayers) in Fig. 2(f,i). The number of  $MoS_2$  layers varies in the range of 1-8 monolayers, which is probably related to nonhomogeneous coating by ammonium molybdate precursor. The measured distance between monolayers is about 6.25 Å, which corresponds well to 6.2-6.3 Å interlayer distance in  $MoS_2$  nanostructures [18, 25].

Alternatively, MoO<sub>3</sub> layer can be deposited on ZnO NWs by DC magnetron sputtering of Mo target in argon-oxygen atmosphere [26]. After sulfidation of ZnO-MoO<sub>3</sub> NWs at 700 °C, morphology of thus obtained core-shell NWs is rather similar to the ones produced by immersion in ammonium heptamolybdate solution (Supplementary materials, Fig. S2). However, MoS<sub>2</sub> shell is usually significantly thicker due to the large amount of deposited MoO<sub>3</sub> precursor (it is difficult to deposit very thin layer of MoO<sub>3</sub> by magnetron sputtering), therefore we can conclude that the immersion method of molybdenum precursor deposition is more preferable in such case compared to the magnetron sputtering.

In our previous work [27], no formation of detectable ZnS layer was observed after the synthesis of ZnO/WS<sub>2</sub> core-shell NWs at 800 °C, and ZnO core remained unaltered and single crystalline after the growth of WS<sub>2</sub> shell (Supplementary materials, Fig. S3). Worth noting that WS<sub>2</sub> growth starts on ZnO surface at the ZnO-WO<sub>3</sub> interface. Probably, WO<sub>3</sub> layer deposited by magnetron sputtering is able to protect ZnO core from sulfidation and/or WO<sub>3</sub> reaction with sulfur is more favourable than ZnO reaction with sulfur.

The phase composition of individual nano-objects such as NWs and 2D nanosheets can be probed by micro-Raman spectroscopy. The results for two samples, a NW and a 2D  $MoS_2$ nanosheet, are reported in Fig. 4. Note that the thickness of the 2D  $MoS_2$  reference nanosheet, measured by AFM, is about 2.6 nm that corresponds to approximately 4 monolayers [28].

The obtained Raman spectrum of the core-shell NW (Fig. 4(d)) is similar to that of the 2D MoS<sub>2</sub> nanosheet (Fig. 4(b)), which confirms the formation of MoS<sub>2</sub> layer on the NWs. The inplane  $E_{2g}^{1}$  mode at 384 cm<sup>-1</sup> and the out-of-plane A<sub>1g</sub> mode at 407 cm<sup>-1</sup> were clearly resolved on the 2D MoS<sub>2</sub> nanosheet (Fig. 4(b)). The same modes  $E_{2g}^{1}$  at 384 cm<sup>-1</sup> and A<sub>1g</sub> at 407 cm<sup>-1</sup> were observed on the core-shell NW (Fig. 4(c,d)). [29, 30]. Note that the large peak at ~521 cm<sup>-1</sup> is the

first order of optical mode at k=0 of the underlying silicon substrate [31]. No Raman bands due to ZnO [32] and ZnS [33] phases were observed because of their weak Raman activity.

4. Conclusions.

In this study we demonstrated a simple process for the production of core-shell ZnO/ZnS/MoS<sub>2</sub> nanowires. A few-layer MoS<sub>2</sub> shell was grown on ZnO NW core by immersing ZnO NWs in ammonium molybdate solution, followed by annealing in a sulfur atmosphere at 700 °C. Two solid state chemical reactions occur during the annealing and result in a formation of ZnS and MoS<sub>2</sub> layers. The annealing at lower temperature (500 °C) is not sufficient for a formation of continuous MoS<sub>2</sub> shell. Morphology and internal structure of the synthesized ZnO/ZnS/MoS<sub>2</sub> core-shell NWs were investigated by SEM and TEM, respectively. The formation of zincblende ZnS interlayer and MoS<sub>2</sub> shell was confirmed by SAED analysis and micro-Raman spectroscopy, respectively.

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Figure 1. SEM images of ZnO NWs, immersed in ammonium heptamolybdate solution and dried (a,b); core-shell ZnO/ZnS/MoS<sub>2</sub> NWs after annealing in sulfur atmosphere at 700°C (c,d); 2D MoS<sub>2</sub> nanosheets grown on a silicon wafer at 700°C (e,f).

Figure 2. TEM images of core-shell NWs annealed in sulfur atmosphere at 500°C (a-c) and 700°C (d-i). Layers of MoS<sub>2</sub> are visible as black lines on top of the NWs surface (f, i).

Figure 3. SAED analysis of core-shell NWs annealed in sulfur atmosphere at 700 °C. The presence of ZnO zincite zone axis <0001> (a,b), ZnS zincblende zone axis <001> (c,d), and MoS<sub>2</sub> molybdenite phases of zone axis <-2201> (e,f) and zone axis <14-53> (g,h) were identified.

Figure 4. AFM image (a) and micro-Raman spectrum (b) of 2D MoS<sub>2</sub> nanosheet on a silicon substrate. Confocal microscope image of ZnO/ZnS/MoS<sub>2</sub> NW on a silicon substrate (c) and the corresponding micro-Raman spectrum (d).

Figures

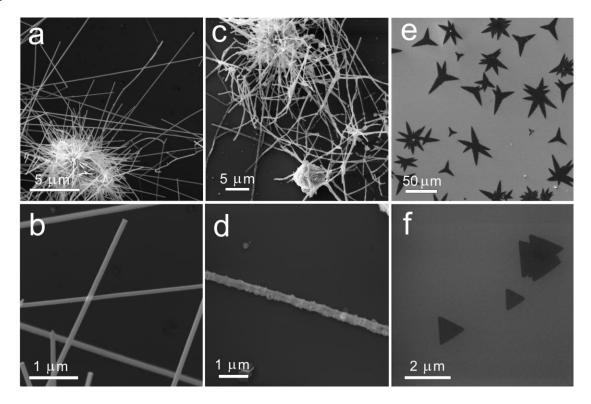
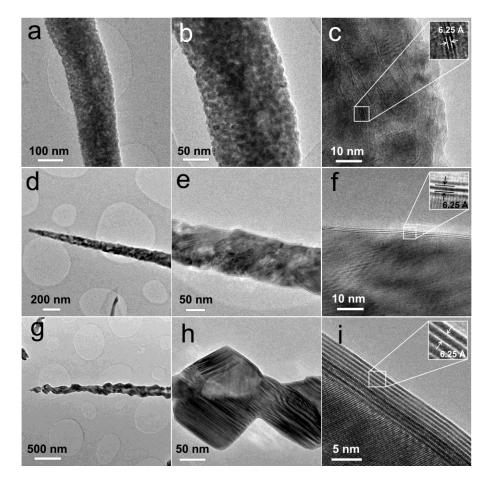


Figure 1.



# Figure 2.

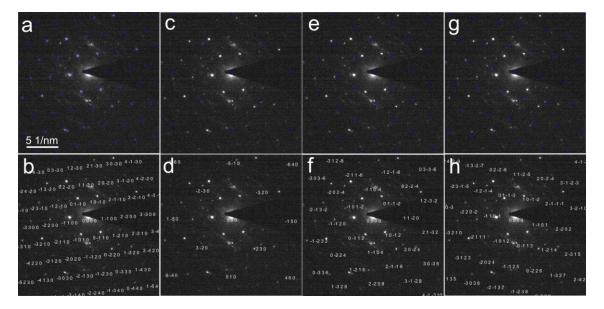


Figure 3.

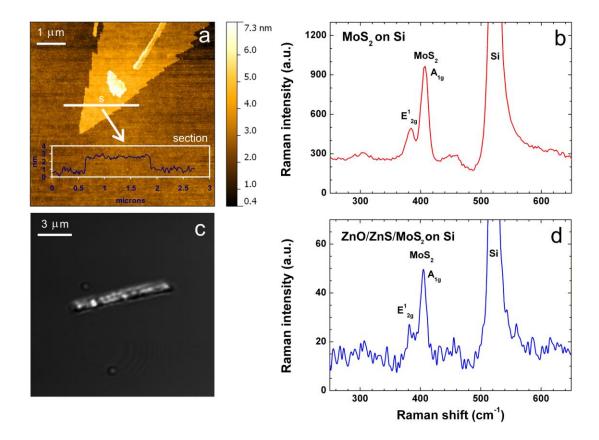


Figure 4.

# Highlights

- A novel synthesis strategy of ZnO/ZnS/MoS<sub>2</sub> core-shell nanowire growth is described.
- A formation of zincblende ZnS interlayer is confirmed by SAED analysis.
- A formation of MoS<sub>2</sub> layers is confirmed by SAED analysis and Raman spectroscopy.

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